ESH1PB, ESH1PC, ESH1PD

Vishay General Semiconductor

AUTOMOTIVE

Available

RoHS COMPLIANT

HALOGEN

FREE

High Current Density Surface Mount Ultrafast Rectifiers



PRIMARY CHARACTERISTICS				
I _{F(AV)}	1.0 A			
V_{RRM}	100 V, 150 V, 200 V			
t _{rr}	25 ns			
V _F	0.90 V			
T _J max.	175 °C			
Package	DO-220AA (SMP)			
Diode variations	Single die			

FEATURES

- · Very low profile typical height of 1.0 mm
- · Ideal for automated placement
- Glass passivated pellet chip junction
- Ultrafast recovery times for high frequency
- Low forward voltage drop, low power loss
- Low thermal resistance
- Meets MSL level 1 per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in secondary rectification and freewheeling for ultrafast switching speeds of AC/AC and DC/DC converters in high temperature conditions for both consumer and automotive applications.

MECHANICAL DATA

Case: DO-220AA (SMP)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and automotive grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	ESH1PB	ESH1PC	ESH1PD	UNIT	
Device marking code		РВ	PC	PD		
Maximum repetitive peak reverse voltage	V_{RRM}	100	150	200	V	
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	1.0			А	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	50			А	
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +175			°C	

ESH1PB, ESH1PC, ESH1PD

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT		
Maximum instantaneous forward voltage	I _F = 0.7 A	T _J = 25 °C	V _F ⁽¹⁾	0.86	V		
	I _F = 1 A			0.90			
Maximum reverse current at rated V _B voltage		T _J = 25 °C	I _B (2)				
iviaximum reverse current at rated v _R voltage		T _J = 125 °C	'IR (=)	25	- μΑ		
Maximum reverse current	V _R = 20 V	T _J = 150 °C	I _R	50	μΑ		
Maximum reverse recovery time	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		t _{rr}	25	ns		
Typical rayaraa raaayary tima	I _F = 1.0 A, V _R = 30 V,	T _J = 25 °C	- t _{rr}	25	ns		
Typical reverse recovery time	$dI/dt = 50 A/\mu s$, $I_{rr} = 10 \% I_{RM}$	T _J = 100 °C		35			
Typical stored charge	$I_F = 1.0 \text{ A}, V_R = 30 \text{ V},$	T _J = 25 °C	0	10	nC		
	$dI/dt = 50 A/\mu s$, $I_{rr} = 10 \% I_{RM}$	T _J = 100 °C	Q _{rr}	15	110		
Typical junction capacitance	4.0 V, 1 MHz		CJ	25	pF		

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	ESH1PB	ESH1PC	ESH1PD	UNIT
Typical thormal registance	R _{0JA} (1)	105			°C/W
Typical thermal resistance	R _{0JM} (2)	15			

Notes

(1) Thermal resistance from junction to ambient on free air

(2) Mounted on 6 mm x 6 mm pad size from junction to mount

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	EIGHT (g) PREFERRED PACKAGE CODE BASE QUANTITY		DELIVERY MODE		
ESH1PB-M3/84A	0.024	84A	3000	7" diameter plastic tape and reel		
ESH1PB-M3/85A	0.024	85A	10 000	13" diameter plastic tape and reel		
ESH1PBHM3/84A (1)	0.024	84A	3000	7" diameter plastic tape and reel		
ESH1PBHM3/85A (1)	0.024	85A	10 000	13" diameter plastic tape and reel		

Note

(1) Automotive grade

Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

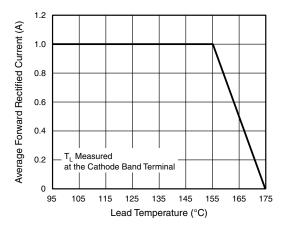


Fig. 1 - Forward Current Derating Curve

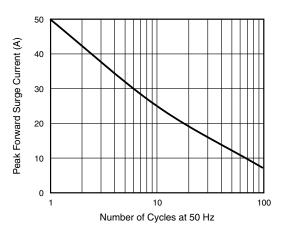


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

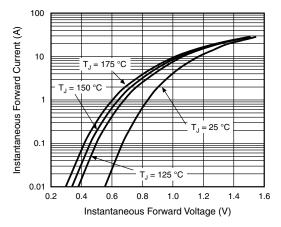


Fig. 3 - Typical Instantaneous Forward Characteristics

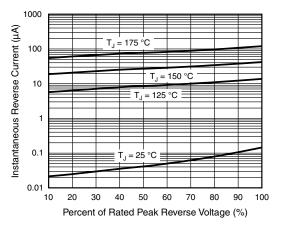


Fig. 4 - Typical Reverse Leakage Characteristics

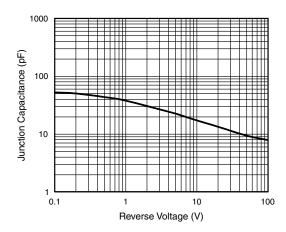


Fig. 5 - Typical Junction Capacitance

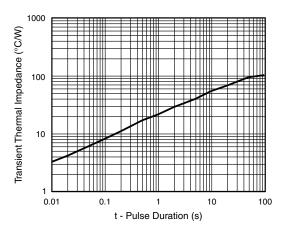


Fig. 6 - Typical Transient Thermal Impedance

ESH1PB, ESH1PC, ESH1PD

Vishay General Semiconductor

0.036 (0.91)

0.024 (0.61)

0.032 (0.80)

0.016 (0.40)

0.050

(1.27)

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

0.012 (0.30)

0.000 (0.00)

0.018 (0.45)

0.006 (0.15)

DO-220AA (SMP) - 0.012 (0.30) REF. Cathode Band 0.053 (1.35) 0.086 (2.18) 0.041 (1.05) 0.074 (1.88) 0.142 (3.61) 0.103 (2.60) 0.126 (3.19) 0.087 (2.20) 0.158 (4.00) 0.146 (3.70) 0.025 0.030 (0.635) (0.762) 0.105 (2.67) 0.013 (0.35) 0.004 (0.10) 0.045 (1.15)

0.033 (0.85)

0.100 (2.54)



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Revision: 13-Jun-16 1 Document Number: 91000

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Vishay:

ESH1PBHM3/84A ESH1PBHM3/85A ESH1PB-M3/84A ESH1PB-M3/85A ESH1PC-M3/85A ESH1PC-M3/85A ESH1PC-M3/85A ESH1PC-M3/85A ESH1PD-M3/85A ESH1PD-M3/85A ESH1PD-M3/85A ESH1PD-M3/85A ESH1PD-M3/85A ESH1PD-M3/85A ESH1PD-M3/85A ESH1PB-E3/85A ESH1PB-E3/85A ESH1PB-E3/85A ESH1PB-E3/85A ESH1PB-E3/85A ESH1PD-E3/85A ESH1PD-E3/85A ESH1PD-E3/85A ESH1PD-E3/85A ESH1PD-E3/85A ESH1PD-E3/85A